

# ESDALC6V1C2

# Quad low capacitance TRANSIL™ array for ESD protection

## **Applications**

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems and cellular phones
- Video equipment

This device is particularly adapted to the protection of symmetrical signals

### **Features**

- 4 unidirectional TRANSIL functions.
- Breakdown voltage V<sub>BB</sub> = 6.1 V min.
- Low diode capacitance (12 pF @ 0 V)
  - Low leakage current (< 500 nA @ 3 V)</li>
  - very small PCB area (1.33 mm²)
- Coated lead free package

### **Benefits**

- High ESD protection level
- High integration
- Suitable for high density boards

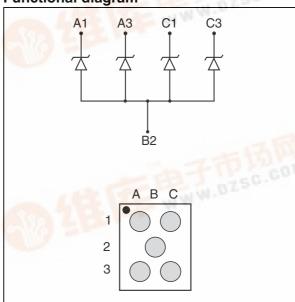
## Description

The ESDALC6V1C2 is a monolithic array designed to protect up to 4 lines againast ESD transients. The device is ideal for applications where both reduced line capacitance and board space saving are required.

TM: TRANSIL is a trademark of STMicroelectronics



### **Functional diagram**



#### Order code

| Part number | Marking |
|-------------|---------|
| ESDALC6V1C2 | WWW ED  |

## Complies with the following standards:

IEC 61000-4-2 15 kV (air discharge)

8 kV (contact discharge)

MIL STD 883E - Method 3015-7: class 3

25 kV (Human body model)

Characteristics ESDALC6V1C2

# 1 Characteristics

Table 1. Absolute maximum ratings ( $T_{amb} = 25^{\circ} C$ )

| Symbol           | Pi  | arameter   |   | Value         | Unit |
|------------------|---|--|---|---------------|------|
| V <sub>PP</sub>  | ESD discharge   | IEC 61000-4-2 air discharge<br>IEC 61000-4-2 contact discharge |   | ± 15<br>± 8   | kV   |
| P <sub>PP</sub>  | Peak pulse power of   | 25   | W |               |      |
| Tj               | Junction temperature  |  |   | 125           | °C   |
| T <sub>stg</sub> | Storage temperature   |  |   | - 55 to +150  | °C   |
| T <sub>L</sub>   | Maximum lead temperature for soldering during 10 s at 5 mm for case |  |   | 260           | °C   |
| T <sub>OP</sub>  | Operating temperature range   |  |   | - 40 to + 125 | °C   |

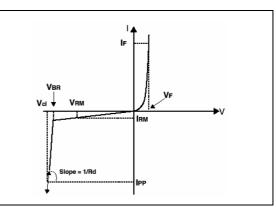
<sup>1.</sup> For a surge greater than the maximum values, the diode will fail in short-circuit

Table 2. Thermal resistance

| Synbol               | Parameter  | Value | Unit |
|----------------------|--|-------|------|
| R <sub>th(j-a)</sub> | Junction to ambient on printed circuit on recommended pad layout | 150   | °C/W |

Table 3. Electrical characteristics

| Symbol          | Parameter                         |  |  |
|-----------------|-----------------------------------|--|--|
| $V_{RM}$        | Stand-of voltage                  |  |  |
| $V_{BR}$        | Breakdown voltage                 |  |  |
| V <sub>CL</sub> | Clamping voltage                  |  |  |
| I <sub>RM</sub> | Leakage current @ V <sub>RM</sub> |  |  |
| I <sub>PP</sub> | Peak pulse current                |  |  |
| αΤ              | Voltage temperature coefficient   |  |  |
| V <sub>F</sub>  | Forward voltage drop              |  |  |

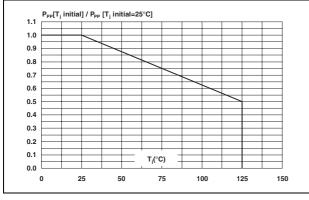


| Туре        | I <sub>RM</sub> @ V <sub>RM</sub> |   | V <sub>BR</sub> @ I <sub>R</sub> |      |    | R <sub>D</sub> | αΤ          | С          |
|-------------|-----------------------------------|---|----------------------------------|------|----|----------------|-------------|------------|
| Туре        | μ <b>A</b> max                    | V | Vmin                             | Vmax | mA | Тур            | 10-4/°C max | pFtyp @0 V |
| ESDALC6V1C2 | 0.5                               | 3 | 6.1                              | 7.2  | 1  | 1              | 5           | 12         |

ESDALC6V1C2 Characteristics

Figure 1. Peak power dissipation versus initial junction temperature

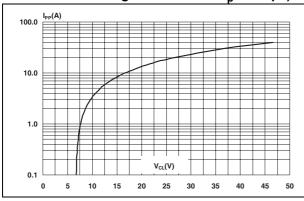
Figure 2. Peak pulse power versus exponential pulse duration  $(T_i initial = 25^{\circ}C)$ 



1000 P<sub>PP</sub>(W)
100 t<sub>P</sub>(µs)
10 100 100

Figure 3. Clamping voltage versus peak pulse current ( $T_j$  initial = 25°C), rectangular waveform  $t_p$  = 2.5  $\mu$ s).

Figure 4. Capacitance versus reverse applied voltage (typical values)



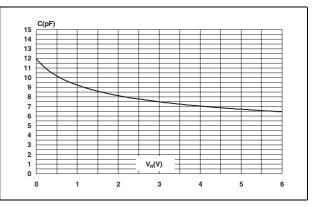
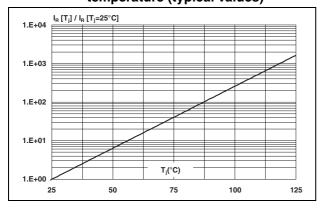
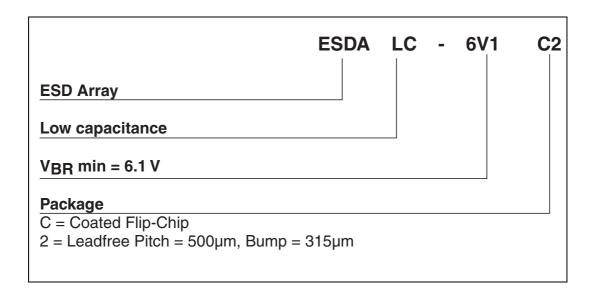


Figure 5. Relative variation of the leakage current versus junction temperature (typical values)



# 2 Ordering information scheme



# 3 Package information

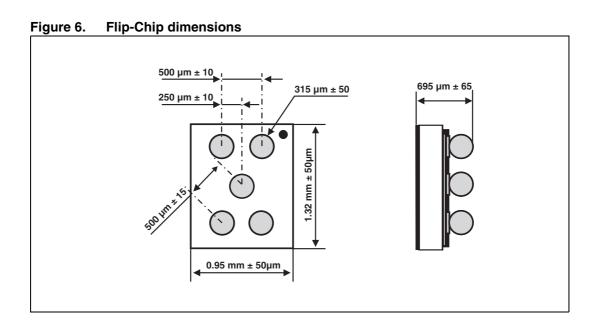


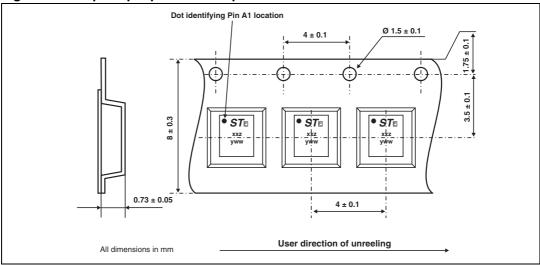
Figure 7. Flip-Chip footprint

Figure 8. Marking

Dot, ST logo xx = marking z = manufacturing location yww = datecode (y = year ww = week)

Solder mask opening recommendation:
340 µm min for 315 µm copper pad diameter

Figure 9. Flip-Chip tape and reel specifications



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

# 4 Ordering information

| Part number | Marking | Package   | Weight | Base qty | Delivery mode |
|-------------|---------|-----------|--------|----------|---------------|
| ESDALC6V1C2 | ED      | Flip-Chip | 2.1 mg | 5000     | Tape and reel |

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Revision history ESDALC6V1C2

# 5 Revision history

| Date        | Revision | Changes          |
|-------------|----------|------------------|
| 07-Aug-2006 | 1        | Initial release. |

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